Specification for Approval

DEVICE NUMBER: BL-R4532N

SAMPLES ATTACHED AREA

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2015/7/6	1.0	1.0	1.0	1.0					Initial Released
						A Barrier			#
					4				
				A			A Partie		

FOR CUSTOMER'S APPROVAL STAMP OR SIGNATURE

APPROVED /	PURCHASE	MANUFACTURE	QUALITY	ENGINEERING

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ISSUED	APPROVED	PREPARED		
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2015.07.06	2015.07.06	2015.07.06		
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BL-R4532N

Features:

Chip material: GaAsP/GaP
 Emitted color: Hi-Eff Red

3. Lens Appearance: Red Diffused

4. Cylindrical shape.

5. Most suitable for use like level indicator.

6. Excellent uniformity of light emittance.

7. Long life solid state reliability.

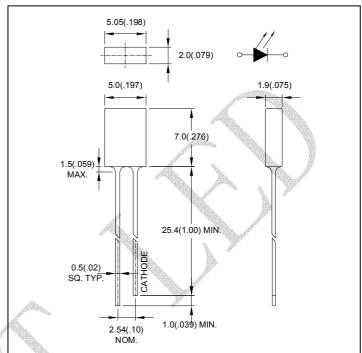
8. Compatible.

9. This product don't contained restriction substance, compliance RoHS standard.

Applications:

- 1. TV set
- 2. Monitor
- 3. Telephone
- 4. Computer
- 5. Circuit board

Package dimensions



Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.25mm (0.01") unless otherwise specified.
- 3. Lead spacing is measured where the leads emerge from the package.
- 4. Specifications are subject to change without notice.

● Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation	Pd	80	mW
Forward Current	I _F	30	mA
Peak Forward Current*1	I _{FP}	150	mA
Reverse Voltage	V _R	5	V
Operating Temperature	Topr	-40°℃~85°℃	
Storage Temperature	Tstg	-40°℃~85°℃	

^{*1}Condition for I_{FP} is pulse of 1/10 duty and 0.1msec width.



BL-R4532N

■ Electrical and optical characteristics(Ta=25°C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Forward Voltage	V_{F}	I _F =20mA	-	2.1	2.6	V
Luminous Intensity	lv	I _F =20mA	-	5.0	-	mcd
Reverse Current	I _R	V _R =5V	-	-	100	μΑ
Peak Wave Length	λр	I _F =20mA	-	640	-	nm
Dominant Wave Length	λd	I _F =20mA	617	-	638	nm
Spectral Line Half-width	Δλ	I _F =20mA	-	35	-	nm
Viewing Angle	2θ _{1/2}	I _F =20mA	-	125	-	deg

Typical electro-optical characteristics curves

Fig.1 Relative intensity vs. Wavelength

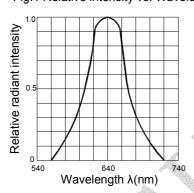


Fig.3 Forward current vs. Forward voltage

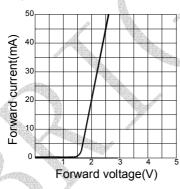


Fig.5 Relative luminous intensity

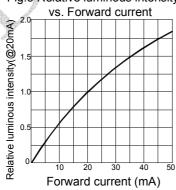


Fig.2 Forward current derating curve vs. Ambient temperature

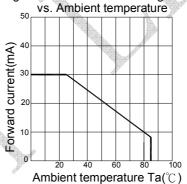


Fig.4 Relative luminous intensity

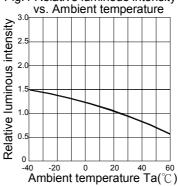
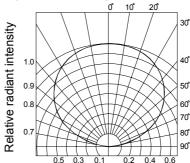


Fig.6 Radiation diagram





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Reliability Test

Classification	Test Item	Reference Standard	Test Conditions	Result
	Operation Life	MIL-STD-750:1026 MIL-STD-883:1005 JIS-C-7021 :B-1	I _F =20mA Ta=+25°ℂ±5°ℂ Test time=1,000hrs	0/32
Endurance Test	High Temperature High Humidity Storage	MIL-STD-202:103B JIS-C-7021 :B-11	Ta=+85°C±5°C RH=90%-95% Test time=240hrs	0/32
	High Temperature Storage	MIL-STD-883:1008 JIS-C-7021 :B-10	ITest time=1 000hrs	
	Low Temperature Storage	JIS-C-7021 :B-12	Low Ta=-45°C±5°C Test time=1,000hrs	0/32
	Temperature Cycling	MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1010 JIS-C-7021 :A-4	Ta: $+85^{\circ}$ (30min) ~ $+25^{\circ}$ (5min) ~ -45° (30min) ~ $+25^{\circ}$ (5min) Test Time : 70min/ctcle 10cycle	0/32
Environmental		MIL-STD-202:107D MIL-STD-750:1051 MIL-STD-883:1011	-45°C±5°C ~+85°C±5°C 20min 20min Test Time=10cycle	0/32
Test	Solder Resistance	MIL-STD-202:201A MIL-STD-750:2031 JIS-C-7021 :A-1	Preheating : 120℃,within 120-180 sec. Operation heating : 255℃±5℃ within 5 sec.260℃ (Max)	0/32
	Solderability	MIL-STD-202F:208D MIL-STD-750D:2026 MIL-STD-883D:2003 JIS C 7021:A-2	T.sol=230±5°C Dwell Time=5±1secs	0/32

Judgment criteria of failure for the reliability

Measuring items	Symbol	Measuring conditions	Judgment criteria for failure
Forward voltage	V _F (V)	I _F =20mA	Over U ¹ x1.2
Reverse current	I _R (uA)	V _R =5V	Over U ¹ x2
Luminous intensity	lv (mcd)	I _F =20mA	Below S ¹ X0.5

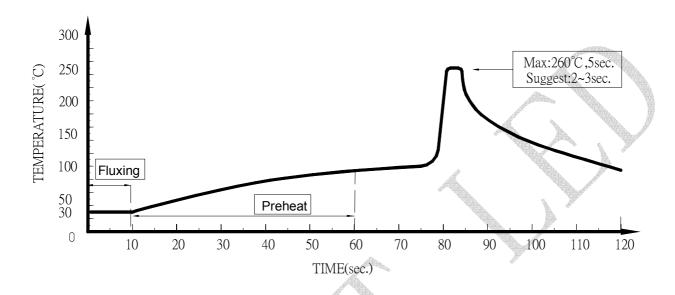
Note: 1. U means the upper limit of specified characteristics. S means initial value.

2. Measurment shall be taken between 2 hours and after the test pieces have been returned to normal ambient conditions after completion of each test.

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Dip Soldering



- 1. Please avoid any external stress applied to the lead-frames and epoxy while the LEDs are at high temperature, especially during soldering
- 2. DIP soldering and hand soldering should not be done more than one time.
- 3. After soldering, avoid the epoxy lens from mechanical shock or vibration until the LEDs are back to room temerature.
- 4. Avoid rapid cooling during temperature ramp-down process
- 5. Although the soldering condition is recommended above, soldering at the lowest possible temperature is feasible for the LEDs

IRON Soldering

300°C Within 3 sec., One time only.